

#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	60	V	
Gate-Source Voltage		V <sub>GS</sub>	±20	v	
Continuous Drain Current <sup>(Note 3)</sup>	T <sub>C</sub> =25°C	1	36		
	Tc=100°C	I <sub>D</sub>	26	А	
Pulsed Drain Current <sup>(Note 1)</sup>	Tc=25°C	I <sub>DM</sub>	120		
Power Dissipation	Tc=25°C	D-	37	10/	
	Tc=100°C	PD	18	— W	
Continuous Drain Current <sup>(Note 4)</sup>	T <sub>A</sub> =25°C		9.5	— A	
	T <sub>A</sub> =70°C	ID	8	A	
Power Dissipation	T <sub>A</sub> =25 <sup>°</sup> C	Pp –	2.5	W	
	T <sub>A</sub> =70 <sup>°</sup> C	FD	1.8	vv	
Single Pulse Avalanche Current <sup>(Note 5)</sup>		las	22	А	
Single Pulse Avalanche Energy <sup>(Note 5)</sup>		E <sub>AS</sub>	36	mJ	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~175	°C	
Thermal Resistance <sup>(Note 4)</sup>	Junction to Case	Rejc	4.1	°C/W	
	Junction to Ambient	R <sub>0JA</sub>	60		



# PJQ4568AP-AU

#### Electrical Characteristics (TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	-	-	V	
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1.5	2.1	3		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =10A	-	11.1	14		
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =6A	-	19.4	.4 25 mΩ		
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	-	-	1	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA	
Dynamic <sup>(Note 6)</sup>		1					
Total Gate Charge	Qg		-	16	21	nC	
Gate-Source Charge	Qgs	V <sub>DS</sub> =30V, I <sub>D</sub> =10A, V <sub>GS</sub> =10V <sup>(Note 2,3)</sup>	-	3	-		
Gate-Drain Charge	$Q_gd$	VGS=10V(((1010 2,0))	-	4	-		
Input Capacitance	Ciss		-	800	1120	pF	
Output Capacitance	Coss	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V, f=1MHz	-	273	410		
Reverse Transfer Capacitance	Crss		-	28	-		
Gate resistance	Rg	f=1MHz	-	1.3	-	Ω	
Turn-On Delay Time	td <sub>(on)</sub>		-	6.5	-	ns	
Turn-On Rise Time	tr	$V_{DS}=30V, I_{D}=10A,$	-	19	-		
Turn-Off Delay Time	td(off)	V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω (Note 2,3)	-	15	-		
Turn-Off Fall Time	tf	(1000 2,5)	-	15	-		
Drain-Source Diode	_			_	_		
Diode Forward Current	I <sub>S</sub>	T 0500	-	-	36		
Pulsed Diode Forward Current	I <sub>SM</sub>	T <sub>C</sub> =25°C	-	-	120	A	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =20A, V <sub>GS</sub> =0V	-	0.9	1.3	V	
Reverse Recovery Time	Trr	VDD=30V,VGS=0V	-	16	-	ns	
Reverse Recovery Charge	Qrr	Is=20A,dIs/dt=100A/us	-	5	-	nC	

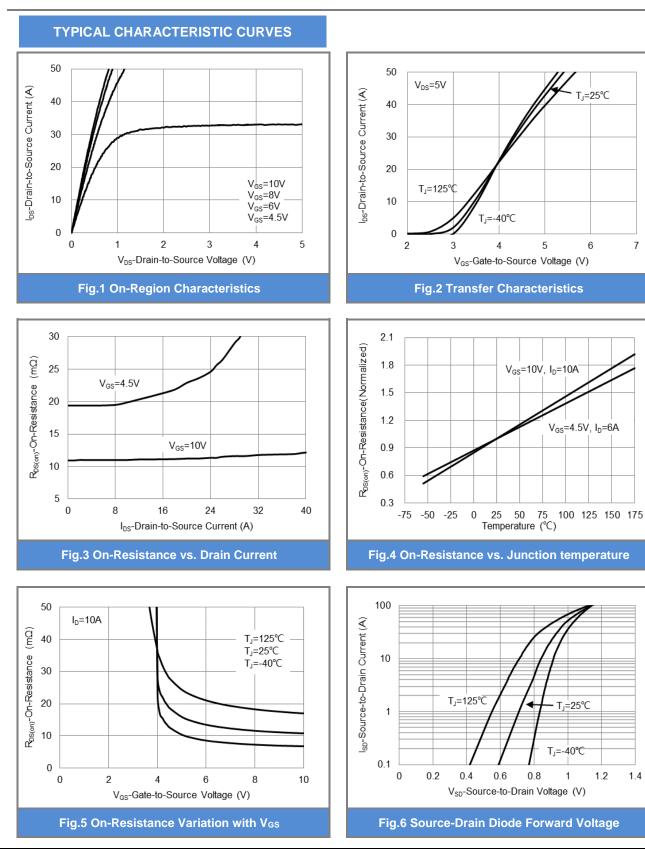
NOTES :

- 1. Pulse width100us, Duty cycle<2%.</td>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an  $R_{\theta JC}$ = 4.1°C/W.
- 4.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 5. E<sub>AS</sub> is calculated based on the condition of L=1mH, I<sub>AS</sub>=8.5A, V<sub>DD</sub>=30V, V<sub>GS</sub>=10V. 100% test at L=0.1mH, I<sub>AS</sub>=22A in production.
- 6. Guaranteed by design, not subject to production testing.

SEMI CONDUCTOR

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1.2

1.4

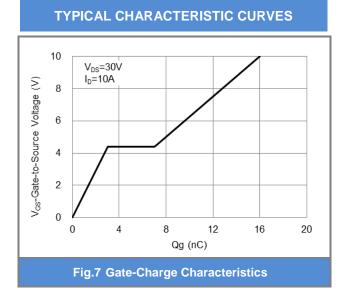
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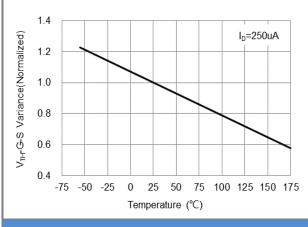
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SEMI CONDUCTOR

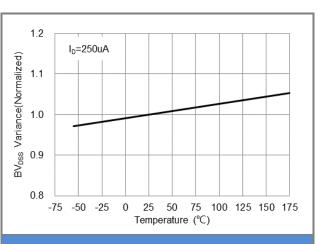
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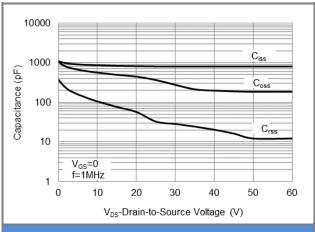


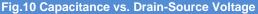


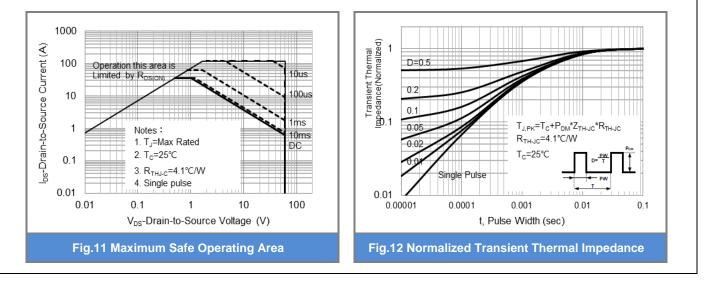












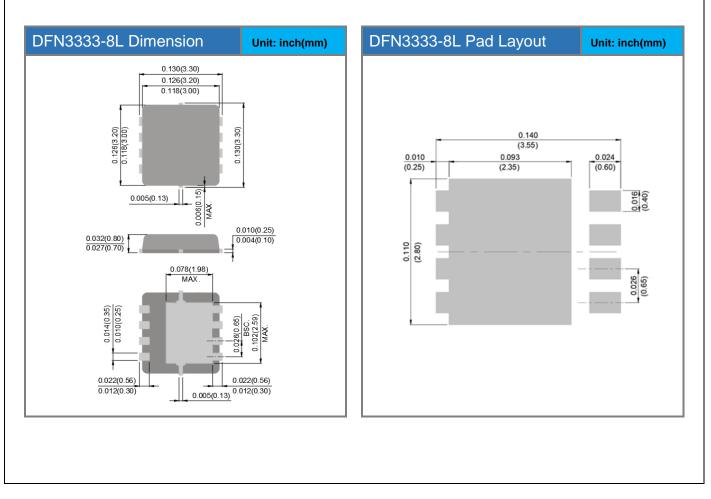


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#### **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking
PJQ4568AP-AU	DFN3333-8L	5K pcs / 13" reel	568A

#### Packaging Information & Mounting Pad Layout





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